

# Schottky Dual Diode

## **PBYL2520CTB**

20V / 25A

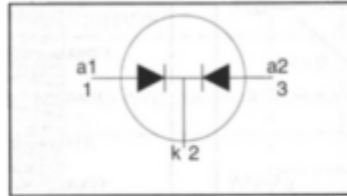
# DATASHEET

OEM – Philips

Source: Philips Databook 1999

**Rectifier diodes  
Schottky barrier**
**PBYL2525CT, PBYL2525CTB series**
**FEATURES**

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

**SYMBOL**

**QUICK REFERENCE DATA**

$$V_R = 20 \text{ V} / 25 \text{ V}$$

$$I_{O(AV)} = 25 \text{ A}$$

$$V_F \leq 0.43 \text{ V}$$

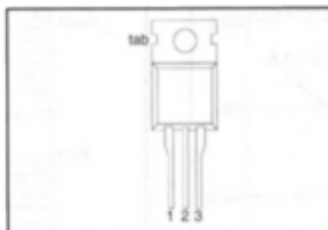
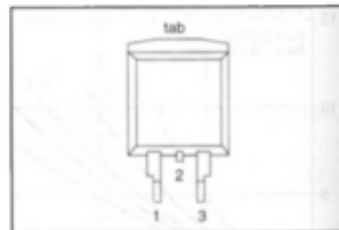
**GENERAL DESCRIPTION**

Dual schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL2525CT series is supplied in the SOT78 (TO220AB) conventional leaded package.  
The PBYL2525CTB series is supplied in the SOT404 surface mounting package.

**PINNING**

PIN	DESCRIPTION
1	gate
2	drain <sup>1</sup>
3	source
tab	drain

**SOT78 (TO220AB)**

**SOT404**

**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
				20CT 20CTB	25CT 25CTB	
$V_{RRM}$	Peak repetitive reverse voltage		-	20	25	V
$V_{RWM}$	Working peak reverse voltage		-	20	25	V
$V_R$	Continuous reverse voltage	$T_{mb} \leq 120 \text{ }^\circ\text{C}$	-	20	25	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$ ; $T_{mb} \leq 119 \text{ }^\circ\text{C}$	-	25		A
$I_{FRM}$	Repetitive peak forward current per diode	square wave; $\delta = 0.5$ ; $T_{mb} \leq 119 \text{ }^\circ\text{C}$	-	25		A
$I_{FSM}$	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$	-	135		A
		$t = 8.3 \text{ ms}$	-	150		A
$I_{SRM}$	Peak repetitive reverse surge current per diode	sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by $T_{jmax}$	-	1		A
$T_j$	Operating junction temperature		-	150		$^\circ\text{C}$
$T_{stg}$	Storage temperature		-65	175		$^\circ\text{C}$

1. It is not possible to make connection to pin 2 of the SOT404 package.

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### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th(j-mb)}$	Thermal resistance junction to mounting base	per diode	-	-	3	K/W
$R_{th(j-a)}$	Thermal resistance junction to ambient	both diodes	-	-	2	K/W
		SOT78 package, in free air	-	60	-	K/W
		SOT404 package, pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

### ELECTRICAL CHARACTERISTICS

All characteristics are per diode at  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 12.5\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	0.36	0.43	V
		$I_F = 12.5\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.38	0.47	V
		$I_F = 25\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.5	0.62	V
		$I_F = 25\text{ A}$	-	0.54	0.66	V
$I_R$	Reverse current	$V_R = V_{RWM}$	-	1	5	mA
		$V_R = V_{RWM}; T_j = 100\text{ }^\circ\text{C}$	-	20	30	mA
$C_d$	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C to } 125\text{ }^\circ\text{C}$	-	600	-	pF

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